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PROCEEDINGS #63: LOW-PROFILE 3D MICROELECTRODES WITH NEAR-UNIFORM CURRENT DENSITY FOR HIGH-RESOLUTION NEURAL STIMULATION

Denys Nikolayev^{1,2}, Wout Joseph¹, Emmeric Tanghe¹, Marleen Welkenhuysen², Carolina Mora Lopez², Thomas Tarnaud¹, Luc Martens¹. ¹ INTEC, imec/Ghent University, 9052 Ghent, Belgium; ² imec, 3001, Heverlee, Belgium

Abstract

Background: Uniform current density electrodes can reduce the risk of electrode corrosion and tissue damage, but existing geometries do not suit thin planar leads.

Objectives: This study examines current density distribution (CDD) on lowprofile electrode designs and proposes an approach to obtain optimal geometries with near-uniform CDD requiring reduced recession depths.

Methods: The electrodes are defined as parametric curves, analyzed using the quasi-static approach, and optimized using the downhill simplex method.

Results: Obtained electrode designs with near-uniform CDD remain low profile and require twice as less recession depths comparing to reference designs.

Conclusion: These electrode shapes are suitable for miniature high-resolution planar DBS leads.

Introduction

Deep brain stimulation (DBS) is an established technique helping us to improve lives and to study the brain. Miniature high-resolution planar shanks [1] are a promising technology that can increase the spatial precision of DBS and hence lessen DBS-induced side effects. However, due to the small electrode surface sizes ($S \leq 10^4 \,\mu\text{m}^2$), the volume of tissue activated (VTA) is usually insufficient. From the point of view of electric field E and potential *V* distribution in electrolytes, one can effectively represent any microelectrode as a point source at distances as little as 50 μ m [2] (cellular level). For a given electrode surface area, VTA depend mainly on the amount of charge that can be safely injected into electrolyte through capacitive transfer and reversible faradic reactions [3].

The electrode shape affects the spatial distribution of current density |J| on the electrode surface that is a cofactor with charge in stimulation induced neural damage [4]. Under stationary conditions, any planar electrode—insulator pair has a non-uniform charge and thus |J| distributions with their maximums at the electrode edges (Fig. 1A). This may lead to localized electrode corrosion or tissue burns at the edges (Fig. 1B) [3]. A few studies quantified how the electrode shape affect its performance and safety [5–8]. However, to the best of our knowledge, none of these studies focused on electrode shapes for thin planar shanks. Uniformizing |J| distributions while avoiding tissue damage [9].

A few fundamental shapes give uniform |J| over their surfaces: a conductive sphere, a conductive half-sphere over an infinite insulator, and a disc electrode that is infinitely recessed into an insulator. However, these approaches are incompatible with thin planar shanks (thickness ~ 20 μ m). A

more appropriate solution was proposed by Ksienski in [10]. It combines a spheroid-like shape of radius *a* recessed into a substrate to a depth *d* = 0.2077*a* (Fig. 1C–E). Still, to ensure the uniform CDD on electrodes of a 100-µm-wide lead ($a \approx 45$ µm), d = 9.3 µm remains unacceptable due to manufacturing and mechanical constraints. Consequently, the maximum recession depth should be limited to a few µm.

In this paper, we characterize, at first, the effect of radius *a* on the average current density |J| of Ksienski's electrodes on a finite-sized planar shank in order to establish the reference values of |J|. Next, using optimization methods, we develop electrodes with near-uniform current density distributions (CDD) that require reduced (1–3 µm for *a* = 45 µm) recession depths.

Methods

We use a quasi-static formulation [11] in cylindrical coordinates (r, φ , z) to study the current density J over the electrodes using the fully hp-adaptive finite element method (hp-FEM) [12]. Considering the axial symmetry of the studied electrodes (e.g. Fig. 1E), we reduce the spatial dimensionality of the problem to R² [i.e. potential $V(\varphi) = \text{const.}$]. The brain tissue is assumed to have homogeneous and isotropic properties with the conductivity $\sigma = 0.1 \text{ S} \cdot \text{m}^{-1}$.

The Laplace's equation $\nabla \cdot \mathbf{J}(r, z) = 0$ governs distributions of the potential *V*, electric field $\mathbf{E} = -\nabla V$, and the current density $\mathbf{J} = (\sigma + j\omega \varepsilon_0 \varepsilon_r)\mathbf{E}$, where ω is the angular frequency and $\varepsilon_0 \approx 8.85 \times 10^{-12} \text{ F} \cdot \text{m}^{-1}$. A unitary potential $V_0 = 1$ (V) models the electrode that extends up to a radius r < a (Fig. 1C). The Neumann boundary condition $\mathbf{n} \cdot \mathbf{J} = 0$ represents the perfect insulator ($r \ge a$). A quadrant of a radius r = 20a truncates the computational domain with a Dirichlet boundary condition V = 0 (Fig. 1C). To avoid the singularity in the model (Fig. 1D), we round the corner formed by the insulator with a radius of 0.05*d*.

The electrode and the shank are defined as analytic curves and optimized numerically to achieve uniform current density (UCD) distributions. Cubic Bézier curves [13] model the electrode surface spanning between the starting point (r = 0, z = 0), and the ending point (a, -d). The starting point is normal to the *z*-axis. Therefore, four parameters a, e_z, e_r , and c_r (Fig. 1D) define the parametric space for each Bézier curve section. We study electrodes containing n [from one (Fig. 1D) to four] Bézier sections. A 2- μ m-thick wall of insulator separates the sections. The curve shape is optimized in terms of Σ_n (a, e_z, e_r, c_r)_n using the downhill simplex method in order to achieve the near-uniform CDD. Considering that the charge is conserved [14], we set the objective to minimize the max_a[].

Results and Discussion

First, we characterize a widely used square planar electrode of area 10^4 - μ m² and 1- μ m thickness for reference purposes. Fig. 1A shows the charge density distribution over the electrode for $V_0 = 1$ V (the edges are beveled with a radius of 0.3 μ m to avoid singularity). Indeed, we see the underutilization of the electrode surface with the charge stored and being injected mostly from the vertices. The distribution of non-reversible redox currents agrees well with CDD (Fig. 1B).

On the other hand, |J| of a planar disk electrode peaks uniformly at the edge; max|J| is about one order of magnitude lower than for the square electrode of the same 10^4 - μ m² surface area. Yet, the edge-to-center ration of |J| is about nine.

The current density induced by a UCD electrode [|J|(r) = const., SD < 0.1%] depends on its radius *a* (Fig. 1F) and can be accurately predicted as |J| $[A \cdot \text{cm}^{-2}] = 10.31a[\mu\text{m}]^{-0.947}$ (adj. $\text{R}^2 = 0.9997$). However, for sufficiently large electrodes ($a > 15 \mu\text{m}$), this design requires recession depths $d > 3 \mu\text{m}$ that exceed the capabilities of the manufacturing process. Therefore, we optimize the UCD design ($a = 45 \mu\text{m}$, Fig. 1E) by splitting it into *n* concentric sections of radii a_n separated by two- μ m-thick insulators. The obtained surface is then optimized in terms of $\Sigma_n(a, e_z, e_n, c_r)_n$ using the downhill simplex method that minimizes max|J|.

Fig. 1G compares an optimized shape (n = 2, $d = 2.3 \mu$ m, 2- μ m-wide insulator at $a_1 = 27 \mu$ m) to a UCD and a planar disk designs of the same radius. Peak $|J| = 0.54 \text{ A} \cdot \text{cm}^{-2}$ is a 74% decrease comparing to a disk electrode, but about twice that of the UCD. The optimized design could be realized on a miniature high-resolution planar shank, as it requires $d \leq 3 \mu$ m. The effect of the proposed electrodes on safe charge injection limits is to be characterized in future studies.

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Figure 1. Electrodes for a planar high-resolution DBS lead ($V_0 = 1$ V). **a.** Surface charge density ρ_q distribution over a square $S = 10^4 \,\mu\text{m}^2$ electrode. **b.** Microphotograph of a $10^4 - \mu\text{m}^2$ TiN electrode corroded at edges due to voltage-transient measurements *in vitro* [max(l) = 1 mA]. The pattern of damage agrees well with ρ_q or, equivalently, **J**] distributions. **c.** Formulation of the problem. **d.** Definition of the electrode geometry and parameters. **e.** UCD electrode of radius *a* recessed to a depth *d* = 0.2077*a* [10]. **f.** Average current density **J**] of a UCD electrode depends on radius *a*. **g.** Current density distributions over radial components of $a = 45 \,\mu\text{m}$ electrodes: optimized ($d = 2.3 \,\mu\text{m}$, max|**J**] = 0.54 A·cm⁻²), disk (max|**J**] = 2.1 A·cm⁻²), and UCD [10] ($d = 9.3 \,\mu\text{m}$).

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